

Smart Two Channel Highside Power Switch for Industrial Applications

Features

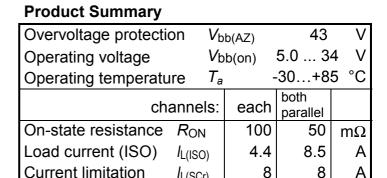
- Overload protection
- Current limitation
- Short circuit protection
- Thermal shutdown
- Overvoltage protection (including load dump)
- Fast demagnetization of inductive loads
- Reverse battery protection¹⁾
- Undervoltage and overvoltage shutdown with auto-restart and hysteresis
- Open drain diagnostic output
- Open load detection in ON-state
- CMOS compatible input
- Loss of ground and loss of V_{bb} protection
- Electrostatic discharge (ESD) protection

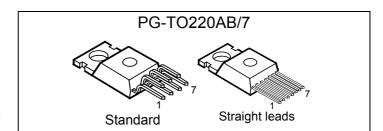
Application

- μC compatible power switch with diagnostic feedback for 12 V and 24 V DC grounded loads in industrial applications
- All types of resistive, inductive and capacitve
- · Replaces electromechanical relays, fuses and discrete circuits

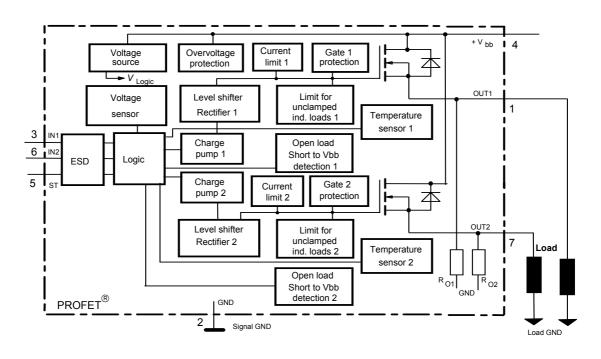
General Description

N channel vertical power FET with charge pump, ground referenced CMOS compatible input and diagnostic feedback, monolithically integrated in Smart SIPMOS® technology. Providing embedded protective functions.





 $I_{L(SCr)}$



¹⁾ With external current limit (e.g. resistor R_{GND} =150 Ω) in GND connection, resistor in series with ST connection, reverse load current limited by connected load.



Pin	Symbol	Function
1	OUT1 (Load, L)	Output 1, protected high-side power output of channel 1
2	GND	Logic ground
3	IN1	Input 1, activates channel 1 in case of logical high signal
4	Vbb	Positive power supply voltage, the tab is shorted to this pin
5	ST	Diagnostic feedback: open drain, low on failure
6	IN2	Input 2, activates channel 2 in case of logical high signal
7	OUT2 (Load, L)	Output 2, protected high-side power output of channel 2

Maximum Ratings at $T_j = 25$ °C unless otherwise specified

Parameter	Symbol	Values	Unit
Supply voltage (overvoltage protection see page 4)	$V_{ m bb}$	43	V
Supply voltage for full short circuit protection $T_{\text{j Start}}$ =-40+150°C	$V_{ m bb}$	34	V
Load dump protection ²⁾ $V_{\text{LoadDump}} = U_{\text{A}} + V_{\text{S}}, U_{\text{A}} = 13.5 \text{ V}$ $R_{\text{I}}^{3)} = 2 \Omega, R_{\text{L}} = 2.7 \Omega, t_{\text{d}} = 200 \text{ ms}, \text{IN} = \text{low or high}$	V _{Load dump} ⁴⁾	60	V
Load current (Short circuit current, see page 5)	<i>I</i> ∟	self-limited	Α
Junction temperature	T _j	+150	°C
Operating temperature range	T _a	-30+85	
Storage temperature range	\mathcal{T}_{stg}	-40+105	
Power dissipation (DC), T _C ≤ 25 °C	P _{tot}	75	W
Inductive load switch-off energy dissipation, single pulse V_{bb} = 12V, $T_{j,start}$ = 150°C, T_{C} = 150°C const. one channel, I_{L} = 4.4 A, Z_{L} = 32 mH, 0 Ω :	E _{AS}	395	mJ
both channels parallel, I_L = 8.5 A, Z_L = 17 mH, 0 Ω :		790	
see diagrams on page 9			
Electrostatic discharge capability (ESD) IN: (Human Body Model) all other pins: acc. MIL-STD883D, method 3015.7 and ESD assn. std. S5.1-1993	V _{ESD}	1.0 2.0	kV
Input voltage (DC)	V _{IN}	-10 +16	V
Current through input pin (DC)	I _{IN}	±2.0	mA
Current through status pin (DC)	I _{ST}	±5.0	
see internal circuit diagrams page 7			

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Supply voltages higher than $V_{bb(AZ)}$ require an external current limit for the GND and status pins, e.g. with a 150 Ω resistor in the GND connection and a 15 k Ω resistor in series with the status pin. A resistor for the protection of the input is integrated.

 $R_{\rm l}$ = internal resistance of the load dump test pulse generator

⁴⁾ V_{Load dump} is setup without the DUT connected to the generator per ISO 7637-1 and DIN 40839



Thermal Characteristics

Parameter and Cond	Symbol	Values			Unit	
			min	typ	max	
Thermal resistance	chip - case, both channels: each channel:	R_{thJC}			1.7 3.4	K/W
	junction - ambient (free air):	R _{thJA}		-	75	

Electrical Characteristics

Parameter and Conditions, each channel	Symbol		Values	;	Unit
at T_j = 25 °C, V_{bb} = 12 V unless otherwise specified		min	typ	max	

Load Switching Capabilities and Characteristics

•						
On-state resistance (pin 4 to 1 o	r 7)					
$I_{L} = 2 A$	<i>T</i> j=25 °C:	Ron		80	100	mΩ
each channel	<i>T</i> j=150 °C:			160	200	
Nominal load current, ISO Norm			3.5	4.4		
$V_{\rm ON} = 0.5 \rm V, \ T_{\rm C} = 85 ^{\circ} \rm C$	each channel:	$I_{L(ISO)}$	6.8	8.5		Α
DOUT	channels parallel:					
Output current (pin 1 or 7) while	GND disconnected	I _{L(GNDhigh)}	-	-	10	mA
or GND pulled up, V_{bb} =30 V, V_{bb}	′ _{IN} = 0, see diagram					
page 8						
Turn-on time IN	N	$t_{\sf on}$	80	200	400	μs
Turn-off time IN	N	$t_{ m off}$	80	200	400	
$R_L = 12 \Omega, T_j = -40 + 150$ °C						
Slew rate on		dV/dt _{on}	0.1	-	1	V/μs
10 to 30% V_{OUT} , $R_L = 12 \Omega$, $T_j =$:-40+150°C					
Slew rate off		-dV/dt _{off}	0.1		1	V/μs
70 to 40% V_{OUT} , $R_{\text{L}} = 12 \Omega$, $T_{\text{j}} =$	=-40+150°C					



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Parameter and Conditions, each channel		Symbol	Values			Unit
at T_j = 25 °C, V_{bb} = 12 V unless other	wise specified		min	typ	max	
			-		•	
Operating Parameters						
Operating voltage ⁵⁾	<i>T</i> _j =-40+150°C:	$V_{\rm bb(on)}$	5.0		34	V
Undervoltage shutdown	<i>T</i> _j =-40+150°C:	$V_{\rm bb(under)}$	3.5		5.0	V
Undervoltage restart	$T_j = -40 + 25$ °C: $T_j = +150$ °C:	V _{bb(u rst)}			5.0 7.0	V
Undervoltage restart of charge see diagram page 13	pump T _j =-40+150°C:	$V_{ m bb(ucp)}$		5.6	7.0	V
Undervoltage hysteresis $\Delta V_{\text{bb(under)}} = V_{\text{bb(u rst)}} - V_{\text{bb(under)}}$		$\Delta V_{ m bb(under)}$		0.2		V
Overvoltage shutdown	<i>T</i> _j =-40+150°C:	V _{bb(over)}	34		43	V
Overvoltage restart	<i>T</i> _j =-40+150°C:	V _{bb(o rst)}	33			V
Overvoltage hysteresis	<i>T</i> _j =-40+150°C:	$\Delta V_{ m bb(over)}$		0.5		V
Overvoltage protection ⁶⁾ I _{bb} =40 mA	<i>T</i> _j =-40+150°C:	$V_{\mathrm{bb}(AZ)}$	42	47		V
Standby current (pin 4)						
$V_{\text{IN}}=0$	<i>T</i> _j =-40+25°C:	I _{bb(off)}		14	30	μA
TIN G	$T_{\rm i}$ = 150°C:	-bb(oii)		17	35	ραι
Leakage output current (include Vin=0	,	I _{L(off)}			12	μА
Operating current (Pin 2) ⁷⁾ , V_{IN} = both channels on, T_I =-40+1		I _{GND}		4	6	mA
Operating current (Pin 2)7)		I_{GND}		2	3	mA

one channel on, $T_1 = -40... + 150$ °C:

⁵⁾ At supply voltage increase up to V_{bb} = 5.6 V typ without charge pump, $V_{OUT} \approx V_{bb}$ - 2 V

⁶⁾ See also $V_{\text{ON(CL)}}$ in table of protection functions and circuit diagram page 8.
7) Add I_{ST} , if $I_{\text{ST}} > 0$, add I_{IN} , if $V_{\text{IN}} > 5.5 \text{ V}$



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Parameter and Conditions, each channel	Symbol		Values	;	Unit
at T_j = 25 °C, V_{bb} = 12 V unless otherwise specified		min	typ	max	•
Protection Functions ⁸⁾	•	•			
Initial peak short circuit current limit (pin 4 to 1 or 7)	I _{L(SCp)}				
τ _j =-40°C: τ _j =25°C: τ _j =+150°C:		11 9 5	18 14 8	25 22 14	Α
Repetitive short circuit shutdown current limit	I _{L(SCr)}				
$T_j = T_{jt}$ (see timing diagrams, page 11)			8		Α
Output clamp (inductive load switch off) at $V_{\text{OUT}} = V_{\text{bb}} - V_{\text{ON(CL)}}$ $I_{\text{L}} = 40$ mA, $T_{\text{j}} = -40+150$ °C:	V _{ON(CL)}	41	47	53	V
Thermal overload trip temperature	T_{jt}	150			°C
Thermal hysteresis	$\Delta T_{\rm jt}$		10		K
Reverse battery (pin 4 to 2) 9)	-V _{bb}			32	V
Reverse battery voltage drop (Vout > Vbb)					
I_{L} = -2.9 A, each channel T_{j} =150 °C:	-V _{ON(rev)}		610		mV
Diagnostic Characteristics					
Open load detection current T_j =-40 °C: (on-condition) T_j =25150°C:	I _{L (OL)}	20 20		400 300	mA
Open load detection voltage ¹⁰) (off-condition) T_j =-40150°C:	$V_{\rm OUT(OL)}$	2	3	4	>
Internal output pull down (pin 1 or 7 to 2), V _{OUT} =5 V, T _j =-40150°C	Ro	4	10	30	kΩ

⁸⁾ Integrated protection functions are designed to prevent IC destruction under fault conditions described in the data sheet. Fault conditions are considered as "outside" normal operating range. Protection functions are not designed for continuous repetitive operation.

Pequires 150 Ω resistor in GND connection. The reverse load current through the intrinsic drain-source diode has to be limited by the connected load. Note that the power dissipation is higher compared to normal operating conditions due to the voltage drop across the intrinsic drain-source diode. The temperature protection is not active during reverse current operation! Input and Status currents have to be limited (see max. ratings page 2 and circuit page 8).

¹⁰⁾ External pull up resistor required for open load detection in off state.



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Parameter and Conditions, each channel	Symbol		Values		
at T_j = 25 °C, V_{bb} = 12 V unless otherwise specified		min	typ	max	·
Input and Status Feedback ¹¹⁾					
Input resistance T_j =-40150°C, see circuit page 7	Rı	2.5	3.5	6	kΩ
Input turn-on threshold voltage $\int T_j = -40+150$ °C:	$V_{IN(T^+)}$	1.7		3.5	V
Input turn-off threshold voltage $\setminus T_j$ =-40+150°C:	$V_{IN(T-)}$	1.5			V
Input threshold hysteresis	$\Delta V_{IN(T)}$		0.5		V
Off state input current (pin 3 or 6), $V_{IN} = 0.4 \text{ V}$, $T_j = -40+150$ °C	I _{IN(off)}	1		50	μΑ
On state input current (pin 3 or 6), V_{IN} = 3.5 V, T_{j} =-40+150°C	I _{IN(on)}	20	50	90	μΑ
Delay time for status with open load after switch off (other channel in off state) (see timing diagrams, page 12), $T_j = -40+150$ °C	$t_{ extsf{d(ST OL4)}}$	100	320	800	μs
Delay time for status with open load after switch off (other channel in on state) (see timing diagrams, page 12), $T_j = -40+150$ °C	$t_{ exttt{d(ST OL5)}}$		5	20	μs
Status invalid after positive input slope (open load) T_j =-40 +150°C:	$t_{d(ST)}$		200	600	μs
Status output (open drain)					
Zener limit voltage T_j =-40+150°C, I_{ST} = +1.6 mA:	$V_{\rm ST(high)}$	5.4	6.1		V
ST low voltage $T_j = -40 + 25$ °C, $I_{ST} = +1.6$ mA:	$V_{\rm ST(low)}$			0.4	
$T_{\rm j}$ = +150°C, $I_{\rm ST}$ = +1.6 mA:				0.6	

 $^{^{\}rm 11)}\,$ If a ground resistor $R_{\rm GND}$ is used, add the voltage drop across this resistor.



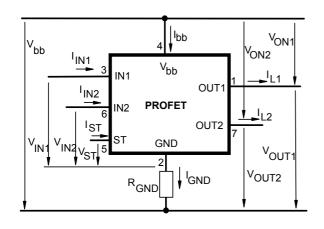
Truth Table

		IN1	IN2	OUT1	OUT2	ST
						ITS621L1
Normal operation		L	L	L	L	Н
		L	Н	L	Н	Н
		Н	L	Н	L	Н
		Н	Н	Н	Н	Н
Open load	Channel 1	L	L	Z	L	H(L ¹²⁾)
		L	Н	Z	Н	`H ´
		Н	Х	Н	X	L
	Channel 2	L	L	L	Z	H(L ¹²⁾)
		Н	L	Н	Z	Н
		X	Н	X	Н	L
Short circuit to V _{bb}	Channel 1	L	L	Н	L	L ¹³⁾
		L	Н	Н	Н	н
		Н	Х	Н	X	H(L ¹⁴⁾)
	Channel 2	L	L	L	Н	Ĺ ¹³)
		Н	L	Н	Н	H .
		X	Н	X	Н	H(L ¹⁴⁾)
Overtemperature	both channel	L	L	L	L	Н
		X	Н	L	L	L
		Н	X	L	L	L
	Channel 1	L	Х	L	Х	Н
		Н	X	L	X	L
	Channel 2	Х	L	Х	L	Н
		X	Н	Х	L	L
Undervoltage/ Overvoltage		X	X	L	L	Н

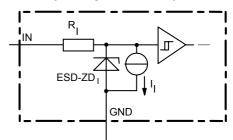
L = "Low" Level H = "High" Level X = don't care

Z = high impedance, potential depends on external circuit Status signal after the time delay shown in the diagrams (see fig 5. page 12...13)

Terms



Input circuit (ESD protection)



ESD zener diodes are not to be used as voltage clamp at DC conditions. Operation in this mode may result in a drift of the zener voltage (increase of up to 1 V).

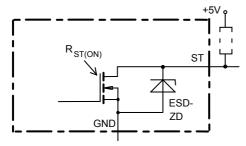
¹²⁾ With additional external pull up resistor

An external short of output to $V_{\rm bb}$, in the off state, causes an internal current from output to ground. If R_{GND} is used, an offset voltage at the GND and ST pins will occur and the V_{ST low} signal may be errorious.

Low resistance to $V_{
m bb}$ may be detected in the ON-state by the no-load-detection



Status output

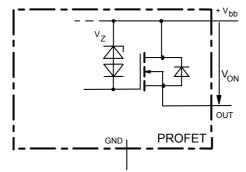


ESD-Zener diode: 6.1 V typ., max 5 mA;

 $R_{ST(ON)}$ < 380 Ω at 1.6 mA, ESD zener diodes are not to be used as voltage clamp at DC conditions.

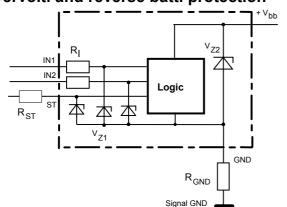
Operation in this mode may result in a drift of the zener voltage (increase of up to 1 V).

Inductive and overvoltage output clamp



V_{ON} clamped to 47 V typ.

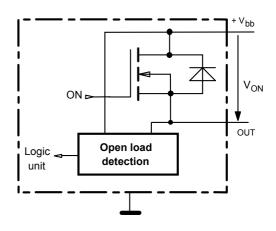
Overvolt. and reverse batt. protection



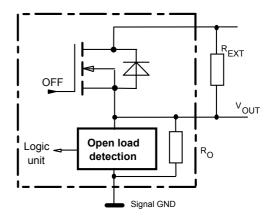
 $V_{\rm Z1}$ = 6.1 V typ., $V_{\rm Z2}$ = 47 V typ., $R_{\rm I}$ = 3.5 k Ω typ, $R_{\rm GND}$ = 150 Ω

Open-load detection

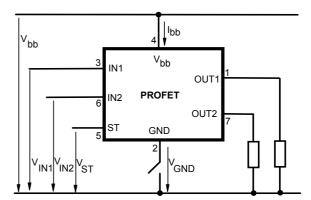
ON-state diagnostic condition: $V_{\text{ON}} < R_{\text{ON}} * I_{\text{L(OL)}}$; IN high



OFF-state diagnostic condition: $V_{OUT} > 3 \text{ V typ.}$; IN low



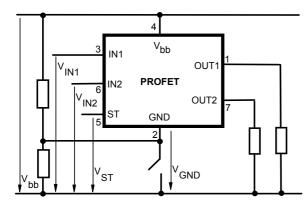
GND disconnect



Any kind of load. In case of Input=high is $V_{\text{OUT}} \approx V_{\text{IN}} - V_{\text{IN}(T+)}$. Due to $V_{\text{GND}} > 0$, no $V_{\text{ST}} =$ low signal available.

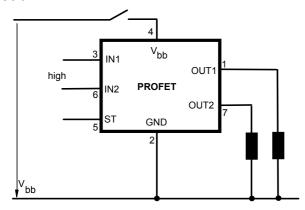


GND disconnect with GND pull up



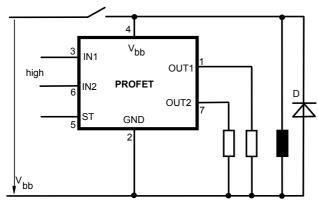
Any kind of load. If $V_{GND} > V_{IN} - V_{IN(T+)}$ device stays off Due to $V_{GND} > 0$, no V_{ST} = low signal available.

V_{bb} disconnect with energized inductive load



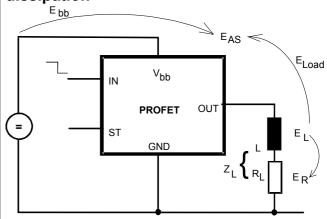
Normal load current can be handled by the PROFET itself.

V_{bb} disconnect with charged external inductive load



If other external inductive loads L are connected to the PROFET, additional elements like D are necessary.

Inductive Load switch-off energy dissipation



Energy stored in load inductance:

$$E_L = \frac{1}{2} \cdot L \cdot I_L^2$$

While demagnetizing load inductance, the energy dissipated in PROFET is

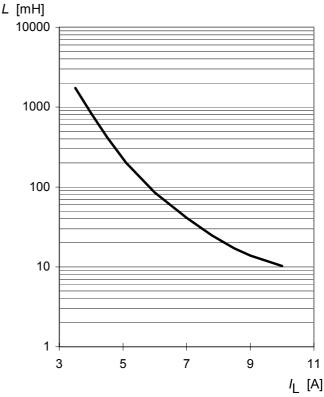
$$E_{AS}$$
= E_{bb} + E_L - E_R = $\int V_{ON(CL)} \cdot i_L(t) dt$,

with an approximate solution for $R_L > 0 \Omega$:

$$E_{\text{AS}} = \frac{I_{\text{L}} \cdot L}{2 \cdot R_{\text{L}}} \cdot \left(V_{\text{bb}} + |V_{\text{OUT(CL)}}| \right) \cdot \ln \left(1 + \frac{I_{\text{L}} \cdot R_{\text{L}}}{|V_{\text{OUT(CL)}}|} \right)$$

Maximum allowable load inductance for a single switch off (both channels parallel)

$$L = f(I_L); T_{j,start} = 150$$
°C, $T_C = 150$ °C const.,
 $V_{bb} = 12 \text{ V}, R_L = 0 \Omega$

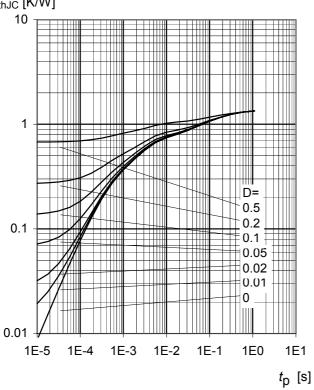




Typ. transient thermal impedance chip case

 $Z_{thJC} = f(t_p)$, one Channel active

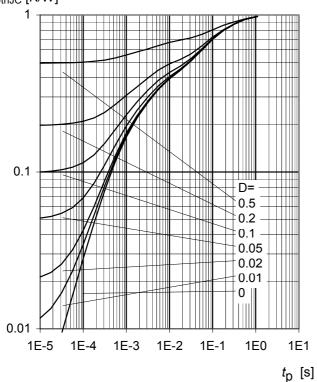




Typ. transient thermal impedance chip case

 $Z_{thJC} = f(t_p)$, both Channel active

Z_{thJC} [K/W]





Timing diagrams

Both channels are symmetric and consequently the diagrams are valid for each channel as well as for permuted channels

Figure 1a: V_{bb} turn on:

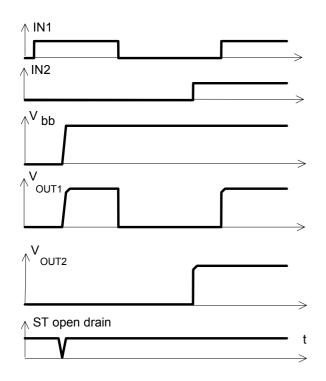


Figure 2a: Switching a lamp:

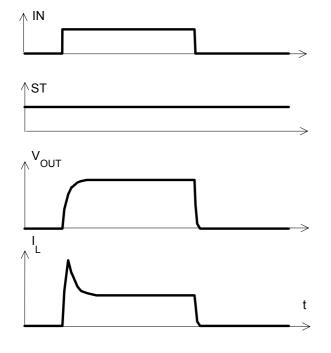


Figure 2b: Switching an inductive load

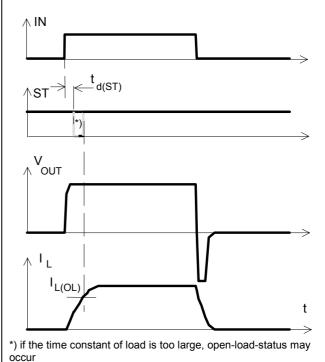
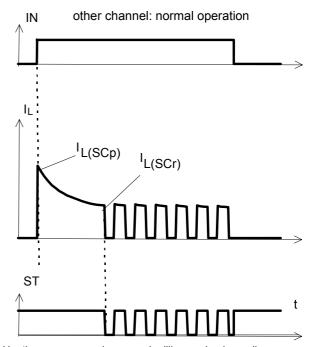


Figure 3a: Short circuit shut down by overtempertature, reset by cooling



Heating up may require several milliseconds, depending on external conditions



Figure 4a: Overtemperature: Reset if $T_i < T_{it}$

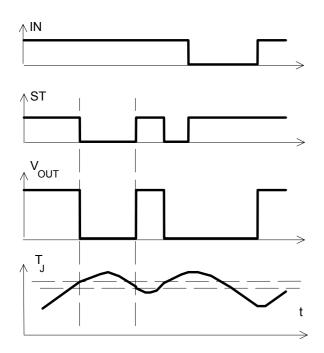


Figure 5a: Open load: detection in ON-state, open load occurs in on-state

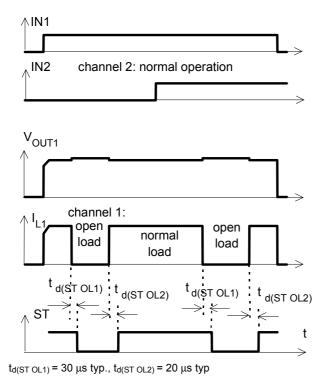


Figure 5b: Open load: detection in ON-state, turn on/off to open load

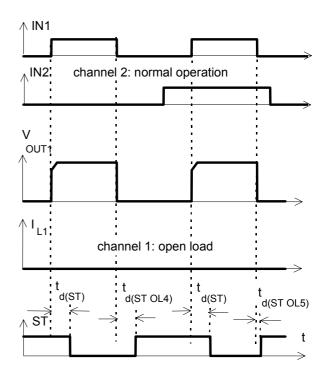


Figure 5c: Open load: detection in ON- and OFF-state (with R_{EXT}), turn on/off to open load

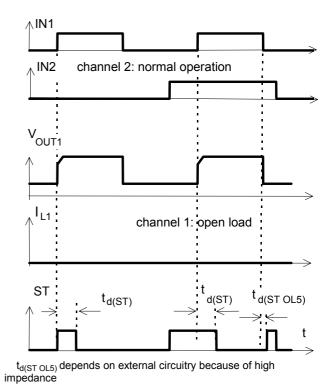




Figure 6a: Undervoltage:

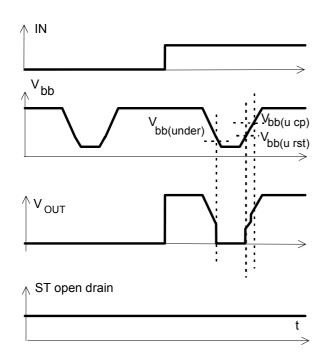


Figure 6b: Undervoltage restart of charge pump

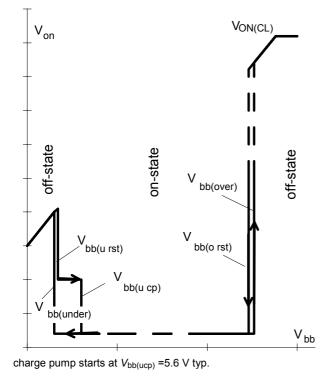
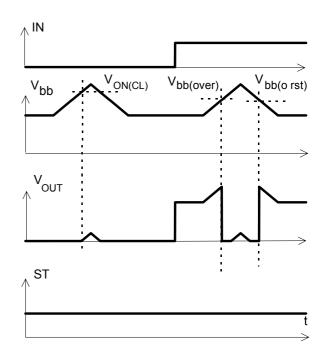


Figure 7a: Overvoltage:

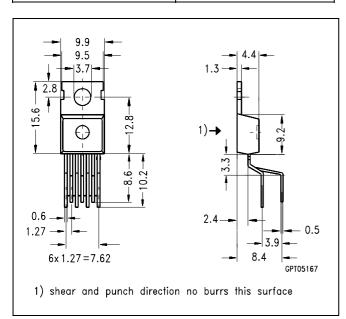




Package and Ordering Code

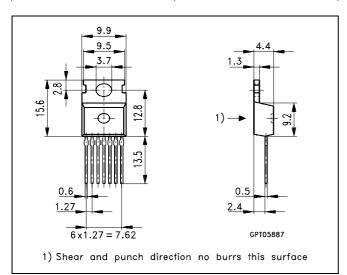
All dimensions in mm

Standard PG-TO220AB/7 Ordering code ITS621L1 SP000219533



PG-TO220AB/7, Opt. E3230 Ordering code

ITS621L1 E3230 SP000221224



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Attention please!

The information herein is given to describe certain components and shall not be considered as a guarantee of characteristics.

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Information

For further information on technology, delivery terms and conditions and prices please contact your nearest Infineon Technologies Office in Germany or our Infineon Technologies Representatives worldwide (see address list).

Warnings

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